

**isc Silicon NPN Power Transistor**

**2SD343**

**DESCRIPTION**

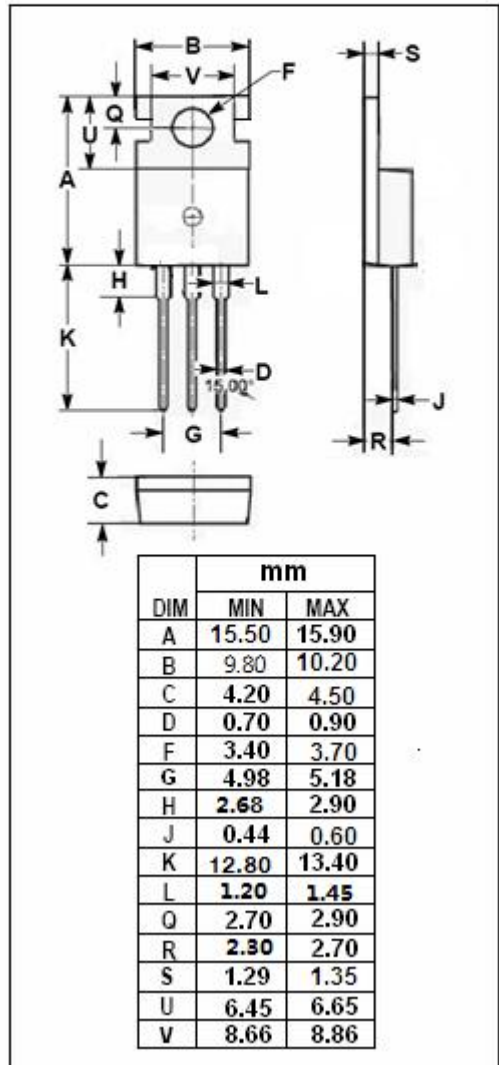
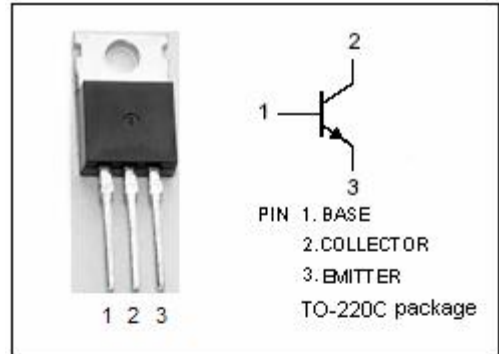
- Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 40V(\text{Min})$
- Low Collector-Emitter Saturation Voltage-  
:  $V_{CE(sat)} = 0.6V(\text{Max}) @ I_C = 2.0A$
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

- Designed for audio and general purpose applications.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

| SYMBOL    | PARAMETER   | VALUE   | UNIT             |
|-----------|---|---------|------------------|
| $V_{CBO}$ | Collector-Base Voltage                              | 70      | V                |
| $V_{CEO}$ | Collector-Emitter Voltage                           | 40      | V                |
| $V_{EBO}$ | Emitter-Base Voltage                                | 6       | V                |
| $I_C$     | Collector Current-Continuous                        | 3       | A                |
| $I_{CM}$  | Collector Current-Peak                              | 5       | A                |
| $I_B$     | Base Current-Peak                                   | 1       | A                |
| $P_C$     | Total Power Dissipation<br>@ $T_C=25^\circ\text{C}$ | 35      | W                |
| $T_J$     | Junction Temperature                                | 150     | $^\circ\text{C}$ |
| $T_{stg}$ | Storage Temperature Range                           | -55~150 | $^\circ\text{C}$ |



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## ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25°C unless otherwise specified

| SYMBOL               | PARAMETER                            | CONDITIONS  | MIN | TYP. | MAX | UNIT |
|----------------------|--------------------------------------|---|-----|------|-----|------|
| V <sub>(BR)CEO</sub> | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> = 10mA; I <sub>B</sub> = 0                           | 40  |      |     | V    |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 2A; I <sub>B</sub> = 0.2A                          |     |      | 0.6 | V    |
| V <sub>BE(sat)</sub> | Base-Emitter Saturation Voltage      | I <sub>C</sub> = 2A; I <sub>B</sub> = 0.2A                          |     |      | 1.0 | V    |
| I <sub>CBO</sub>     | Collector Cutoff Current             | V <sub>CB</sub> = 70V; I <sub>E</sub> = 0                           |     |      | 100 | μ A  |
| I <sub>EBO</sub>     | Emitter Cutoff Current               | V <sub>EB</sub> = 6V; I <sub>C</sub> = 0                            |     |      | 100 | μ A  |
| h <sub>FE-1</sub>    | DC Current Gain                      | I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 1V                         | 60  |      | 320 |      |
| h <sub>FE-2</sub>    | DC Current Gain                      | I <sub>C</sub> = 2A; V <sub>CE</sub> = 1V                           | 20  |      |     |      |
| f <sub>T</sub>       | Current-Gain—Bandwidth Product       | I <sub>E</sub> =0.5A; V <sub>CE</sub> = 5V                          | 5   |      |     | MHz  |
| C <sub>OB</sub>      | Output Capacitance                   | I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f <sub>test</sub> = 1MHz |     | 60   |     | pF   |

## Switching Times

|                  |              |   |  |  |     |     |
|------------------|--------------|---|--|--|-----|-----|
| t <sub>on</sub>  | Turn-on Time | I <sub>C</sub> = 2A; R <sub>L</sub> = 10 Ω,<br>I <sub>B1</sub> = -I <sub>B2</sub> = 0.2A, V <sub>CC</sub> = 20V |  |  | 1.2 | μ s |
| t <sub>stg</sub> | Storage Time |   |  |  | 2.0 | μ s |
| t <sub>f</sub>   | Fall Time    |   |  |  | 1.1 | μ s |

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